36V INPUT VOLTAGE DETECTOR

NO.EA-187-160229

OUTLINE

R3119x Series are CMOS-based 36V input (absolute maximum ratings: 50V) voltage detector with high detector threshold accuracy and ultra-low supply current. Each of those ICs consists of a voltage reference unit, a comparator, resistors for detector threshold setting, an output driver and a hysteresis circuit.

There are two types: R3119xxxxA has the C_D pin for setting the output delay time. R3119xxxxE has the SENSE pin.

The supply current of IC is only 3.3μA. The detector threshold is fixed in the IC and can be set with a step of 0.1V in the range of 2.3V to 12V. Detector threshold accuracy is 1.5%. The output type is Nch Open drain type.

The R3119x is offered in a small-size 6-pin DFN(PL)1820-6 package in addition to a 5-pin SOT-23-5 package.

FEATURES

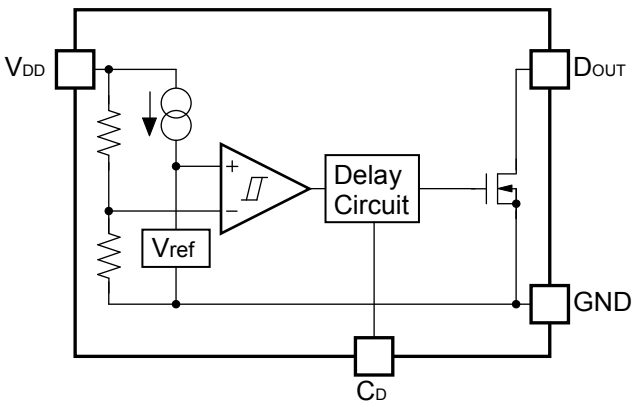
- Supply Current ..... Typ. 3.3μA
- Operating Voltage Range ..... 1.2V to 36.0V (C_D pin type: R3119xxxxA)
  2.1V to 6.0V (SENSE pin type: R3119xxxxE)
- Operating Temperature Range ..... −40°C to 105°C
- Detector Threshold Range ..... 2.3V to 12.0V (0.1V steps)
  (For other voltages, please refer to MARK INFORMATIONS.)
- Detector Threshold Accuracy ..... ±1.5% (T_{opt}=25°C)
- Temperature-Drift Coefficient of Detector Threshold ..... Typ. ±100ppm/°C
- Output Delay Time (Power ON Reset Delay Time) ..... Typ. 85ms (C_D=0.01μF, C_D pin type)
- Output Delay Time Accuracy ..... −50% to 80% (C_D pin type: R3119xxxxA)
- Output Type ..... Nch Open Drain
- Package ..... SOT-23-5, DFN(PL)1820-6

APPLICATIONS

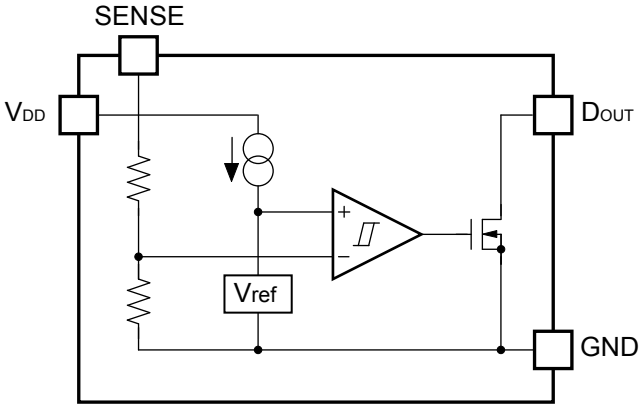
- CPU and Logic Circuit Reset
- Battery Checker
- Battery Back-up Circuit
- Power Failure Detector for Digital home appliances

BLOCK DIAGRAMS

R3119xxxxA



R3119xxxxE



SELECTION GUIDE

The package type, the detector threshold and the version for the ICs can be selected at the users' request.

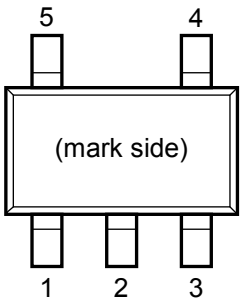
Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R3119Nxxx∗-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes
R3119Kxxx∗-TR	DFN(PL)1820-6	5,000 pcs	Yes	Yes

xxx: The detector threshold can be designated in the range from 2.3V(023) to 12.0V(120) in 0.1V steps.
(For other voltages, please refer to MARK INFORMATIONS.)

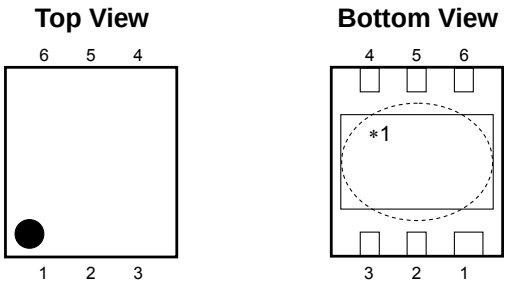
∗ : Designation of Version
(A) with C_D pin type
(E) with SENSE pin type

PIN CONFIGURATIONS

●SOT-23-5



●DFN(PL)1820-6



PIN DESCRIPTIONS

- **SOT-23-5**

Pin No.	Symbol	Description	
1	V_{DD}	Input Pin	
2	GND*	Ground Pin	
3	GND*	Ground Pin	
4	D_{OUT}	Output Pin ("L" at detection)	
5	C_D	R3119NxxxA	Connecting pin with external capacitor for setting delay time
	SENSE	R3119NxxxE	Voltage Detector Voltage Sense Pin

∗) No. 2 and No.3 pins must be wired to the GND plane when it is mounted on board.

- **DFN(PL)1820-6**

Pin No.	Symbol	Description	
1	GND	Ground Pin	
2	NC	No Connection	
3	V_{DD}	Input Pin	
4	C_D	R3119KxxxA	Connecting pin with external capacitor for setting delay time
	SENSE	R3119KxxxE	Voltage Detector Voltage Sense Pin
5	NC	No Connection	
6	D_{OUT}	Output Pin ("L" at detection)	

∗) Tab is GND level. (They are connected to the reverse side of this IC.) The tab is better to be connected to the GND, but leaving it open is also acceptable.

ABSOLUTE MAXIMUM RATINGS

Symbol	Item		Rating	Unit
V_{DD}	Supply Voltage	R3119xxxxA	−0.3 to 50.0	V
		R3119xxxxE	−0.3 to 7.0	
V_{OUT}	Output Voltage (D_{OUT} Pin)		−0.3 to 7.0	V
V_{CD}	Output Voltage (C_D Pin)	R3119xxxxA	−0.3 to 7.0	V
V_{SENSE}	Input Voltage (SENSE Pin)	R3119xxxxE	−0.3 to 50.0	
I_{OUT}	Output Current (D_{OUT} Pin)		20	mA
P_D	Power Dissipation (SOT-23-5)*		420	mW
	Power Dissipation (DFN(PL)1820-6)*		880	
Topt	Operating Temperature Range		−40 to 105	°C
Tstg	Storage Temperature Range		−55 to 125	°C

∗) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.
The functional operation at or over these absolute maximum ratings is not assured.

ELECTRICAL CHARACTERISTICS

- **R3119xxxxA (C_D pin type)**

The specification in ☐ is checked and guaranteed by design engineering at –40°C ≤ Topt ≤ 105°C.

Topt=25°C

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
$-V_{DET}$	Detector Threshold	V_{DD} pin	Topt=25°C	×0.985		×1.015	V
			–40°C ≤ Topt ≤ 105°C	☐×0.970		☐×1.020	
V_{HYS}	Detector Threshold Hysteresis			☐3.5	5	☐6.5	%
I_{SS}	Supply Current	V_{DD}= $-V_{DET}$–0.1V			3.3	☐5.6	µA
		V_{DD}= $-V_{DET}$+1.0V			3.3	☐5.5	
V_{DDH}	Maximum Operating Voltage					36	V
V_{DDL}	Minimum Operating Voltage*	Topt=25°C				1.2	V
		–40°C ≤ Topt ≤ 105°C				☐1.25	
I_{OUT}	Output Current (Driver Output Pin)	V_{DD}=1.5V, V_{DS}=0.05V		☐230			µA
		2.3V ≤ $-V_{DET}$ < 2.6V	V_{DD}=2.2V V_{DS}=0.5V	☐2.8			mA
		2.6V ≤ $-V_{DET}$ < 3.0V	V_{DD}=2.5V V_{DS}=0.5V	☐3.3			
		3.0V ≤ $-V_{DET}$	V_{DD}=2.9V V_{DS}=0.5V	☐3.5			
I_{LEAK}	Nch Driver Leakage Current	V_{DD}=36V, V_{DS}=6.0V				☐0.2	µA
$\Delta-V_{DET}/\Delta Topt$	Detector Threshold Temperature Coefficient	–40°C ≤ Topt ≤ 105°C			☐±100		ppm /°C
tdelay	Detector Output Delay Time	V_{DD}=1.5V → $-V_{DET}$+2.0V C_D=0.01µF		☐45	85	☐150	ms

All of unit are tested and specified under load conditions such that Tj≈Topt=25°C except for Detector Threshold Temperature Coefficient.

∗) This value is the minimum input voltage when the output voltage is 0.1V or less at detection.
(The pull-up resistance; 100kΩ, the pull-up voltage; 5.0V)

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

- **R3119xxxxE (SENSE pin type)**

The specification in ☐ is checked and guaranteed by design engineering at –40°C ≤ Topt ≤ 105°C.

Topt=25°C

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
V_{DD}	Operating Voltage			2.1*		6	V
$-V_{DET}$	Detector Threshold	SENSE pin V_{DD}=6V	Topt=25°C	×0.985		×1.015	V
			–40°C ≤ Topt ≤ 105°C	×0.970		×1.020	
V_{HYS}	Detector Threshold Hysteresis	V_{DD}=6V		3.5	5	6.5	%
I_{SS}	Supply Current	V_{DD}=6V, V_{SENSE}= $-V_{DET}$–0.1V			3.3	5.5	µA
		V_{DD}=6V, V_{SENSE}= $-V_{DET}$+1.0V			3.3	5.5	
R_{SENSE}	Sense Resistor			4.5		120	MΩ
I_{OUT}	Output Current (Driver Output Pin)	V_{SENSE} < $-V_{DET}$	V_{DD}=2.1V V_{DS}=0.05V	420			µA
		V_{SENSE} < $-V_{DET}$	V_{DD}=2.2V V_{DS}=0.5V	2.8			mA
I_{LEAK}	Nch Driver Leakage Current	V_{DD}=6V, V_{SENSE}=36V, V_{DS}=6.0V				0.2	µA
$\Delta-V_{DET}/\Delta Topt$	Detector Threshold Temperature Coefficient	–40°C ≤ Topt ≤ 105°C			±100		ppm /°C
t_{PLH}	Output Delay Time	V_{DD}=6V V_{SENSE}=1.5V → $-V_{DET}$+2.0V			15		µs
V_{SENSE}	Input Voltage (SENSE Pin)			0		36	V

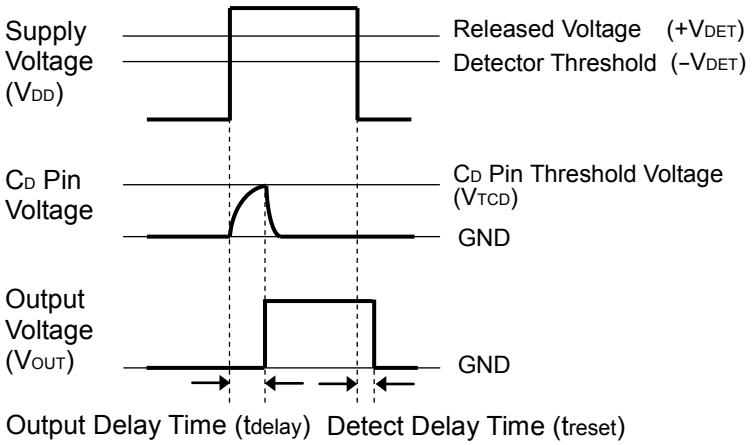
All of unit are tested and specified under load conditions such that Tj≈Topt=25°C except for Detector Threshold Temperature Coefficient and Output Delay Time.

∗) Minimum operating voltage of "SENSE pin type" is minimum supply voltage to obtain correct detection voltage.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

TIMING CHART



When the supply voltage, which is higher than released voltage, is forced to V_{DD} pin, charge to an external capacitor starts, then C_D pin voltage increases. Until the C_D pin voltage reaches to C_D pin threshold voltage, output voltage maintains "L". When the C_D pin voltage becomes higher than C_D pin threshold voltage, output voltage is reversed from "L" to "H". Where the time interval between the rising edge of supply voltage and output voltage reverse point means output delay time.

When the output voltage reverses from "L" to "H", the external capacitor starts to discharge. Therefore, when lower voltage than the detector threshold voltage is forced to V_{DD} pin, the output voltage reverses from "H" to "L" thus the detect delay time is constant not being affected by the external capacitor.

- **Output Delay Time**

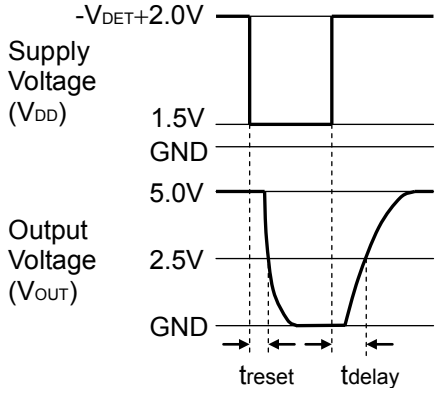
Output Delay Time (t_{delay}) can be calculated with the next formula using the external capacitor:

$t_{delay}(s) = 8.5 \times 10^6 \times C_D(F)$

DEFINITION OF OUTPUT DELAY TIME

Output Delay Time (t_{delay}) is defined as follows:

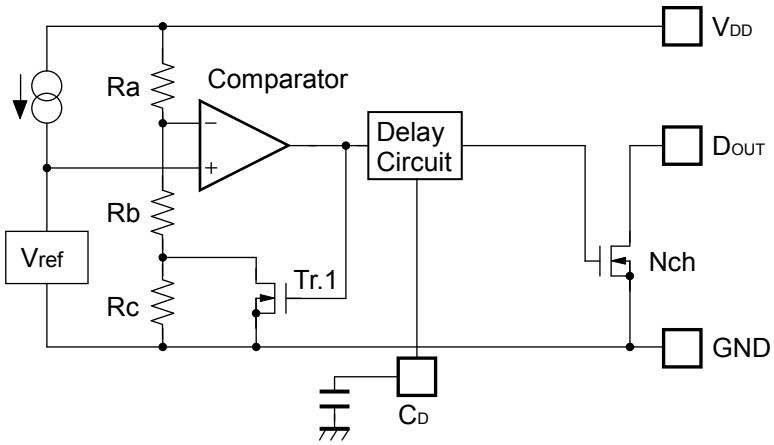
Under the condition of the output pin (D_{OUT}) is pulled up through a resistor of 100kΩ to 5V, the time interval between the rising edge of V_{DD} pulse from 1.5V to (-V_{DET})+2.0V pulse voltage is supplied, the becoming of the output voltage to 2.5V.



R3119xxxxA

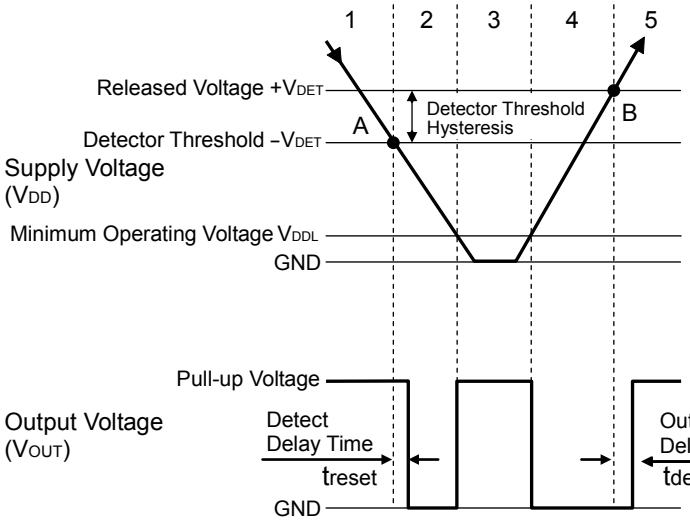
OPERATION

- **Operation of R3119xxxxA (C_D pin type)**



D_{OUT} pin should be pulled-up to an external voltage level.

Block Diagram of External Capacitor Connection



Step	1	2	3	4	5
Comparator (−) Pin Input Voltage	I	II	II	II	I
Comparator Output	L	H	Indefinite	H	L
Tr.1	OFF	ON	Indefinite	ON	OFF
Output Tr. (Nch)	OFF	ON	Indefinite	ON	OFF

$$\text{I} \quad \frac{Rb+Rc}{Ra+Rb+Rc} \times V_{DD}$$

$$\text{II} \quad \frac{Rb}{Ra+Rb} \times V_{DD}$$

Operation Diagram

- **Explanation of operation**

Step 1. The output voltage is equal to the pull-up voltage.

Step 2. At Point "A", $V_{ref} \geq V_{DD} \times (Rb+Rc)/(Ra+Rb+Rc)$ is true, as a result, the output of comparator is reversed from "L" to "H", therefore the output voltage becomes the GND level. The voltage level of Point A means a detector threshold voltage ($-V_{DET}$).

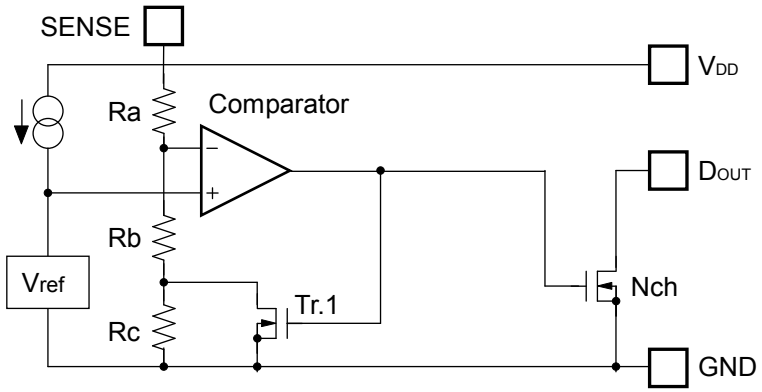
Step 3. When the supply voltage is lower than the minimum operating voltage, the operation of the output transistor becomes indefinite. The output voltage is equal to the pull-up voltage.

Step 4. The output voltage is equal to the GND level.

Step 5. At Point "B", $V_{ref} \leq V_{DD} \times Rb/(Ra+Rb)$ is true, as a result, the output of comparator is reversed from "H" to "L", then the output voltage is equal to the pull-up voltage. The voltage level of Point B means a released voltage ($+V_{DET}$).

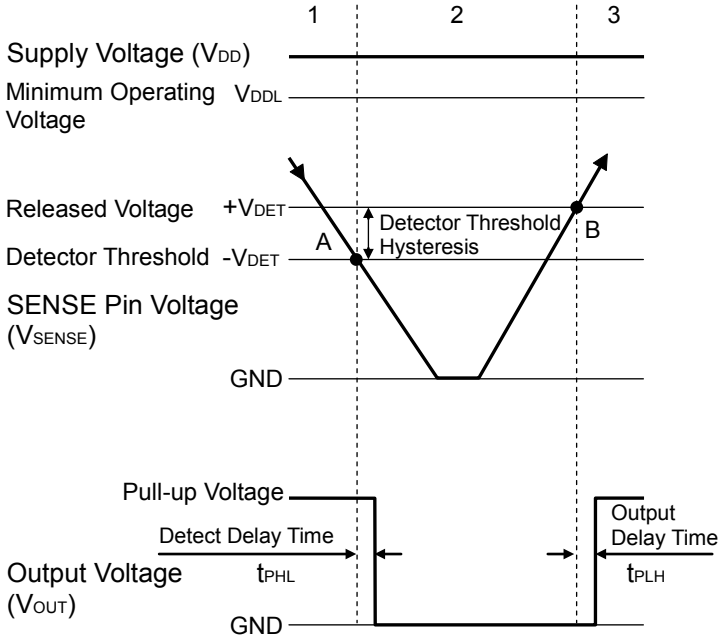
∗) The difference between a released voltage and a detector threshold voltage is a detector threshold hysteresis.

- **Operation of R3119xxxxE (SENSE pin type)**



DOUT pin should be pulled-up to an external voltage level.

Block Diagram



Step	1	2	3
Comparator (−) Pin Input Voltage	I	II	I
Comparator Output	L	H	L
Tr.1	OFF	ON	OFF
Output Tr. (Nch)	OFF	ON	OFF

$$\text{I} \quad \frac{Rb+Rc}{Ra+Rb+Rc} \times V_{SENSE}$$

$$\text{II} \quad \frac{Rb}{Ra+Rb} \times V_{SENSE}$$

Operation Diagram

- **Explanation of operation**

Step 1. SENSE pin voltage is larger than detector threshold; the output voltage is equal to the pull-up voltage.

Step 2. At Point "A", $V_{ref} \geq V_{SENSE} \times (Rb+Rc)/(Ra+Rb+Rc)$ is true, as a result, the output of comparator is reversed from "L" to "H", therefore the output voltage becomes the GND level. The voltage level of Point A means a detector threshold voltage ($-V_{DET}$). (When the supply voltage is higher than the minimum operating voltage, the output voltage is equal to the GND level.)

Step 3. At Point "B", $V_{ref} \leq V_{SENSE} \times Rb/(Ra+Rb)$ is true, as a result, the output of comparator is reversed from "H" to "L", then the output voltage is equal to the pull-up voltage. The voltage level of Point B means a released voltage ($+V_{DET}$).

∗) The difference between a released voltage and a detector threshold voltage is a detector threshold hysteresis.

Power supply injection order

The R3119xxxxE Series supervise the voltage of the SENSE pin. V_{DD} pin and SENSE pin can be used at the same voltage level. Likewise, V_{DD} pin and SENSE pin can be used at the different voltage level. If the V_{DD} pin and SENSE pin are used at different voltage level, regarding the start-up sequence, force the voltage level to V_{DD} pin prior to the SENSE pin.

If the SENSE pin voltage is equal or more than the released voltage ($+V_{DET}$), D_{OUT} pin becomes "H"(Fig.1). Besides, a voltage beyond V_{DD} pin is also acceptable to SENSE pin.

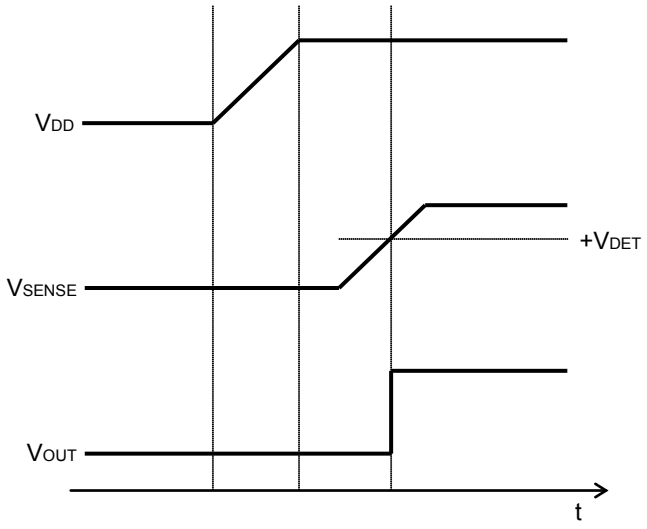
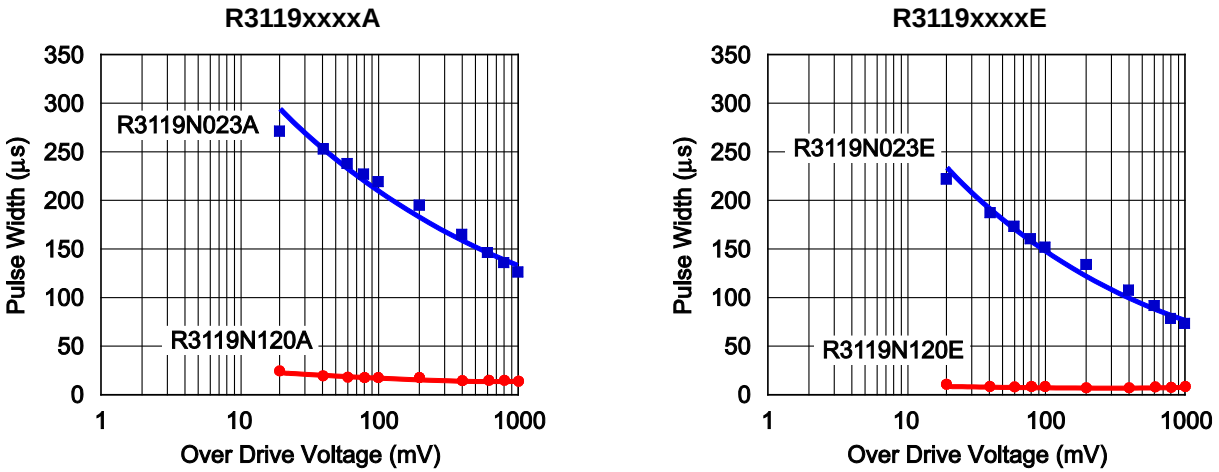
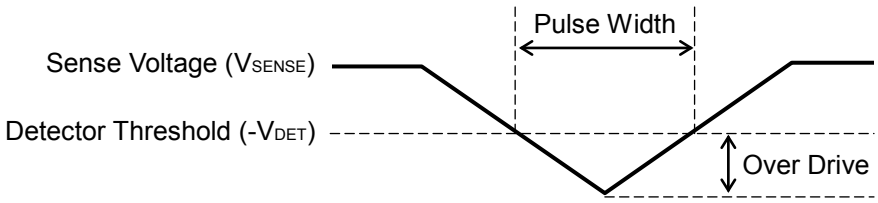


Fig.1 Turn on sequence

Detector Operation vs. glitch input voltage to the V_{DD} pin or SENSE pin

When the R3119x is at released, if the pulse voltage which the detector threshold or lower voltage, the graph below means that the relation between pulse width and the amplitude of the swing to keep the released state for the R3119x.





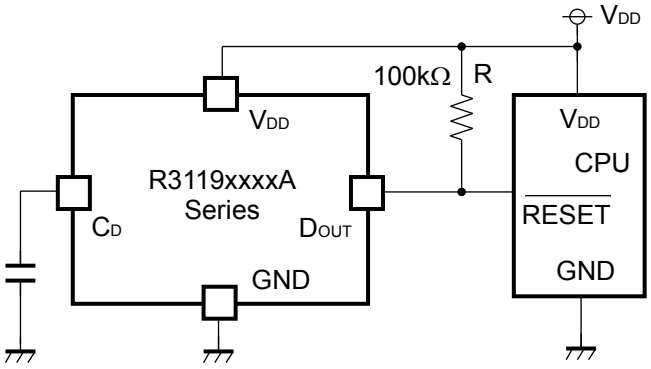
V_{SENSE} Input Waveform

This graph shows the maximum pulse conditions to keep the released voltage. If the pulse with larger amplitude or wider width than the graph above, is input to the V_{DD} pin (R3119xxxxA) or to the SENSE pin (R3119xxxxE), the reset signal may be output.

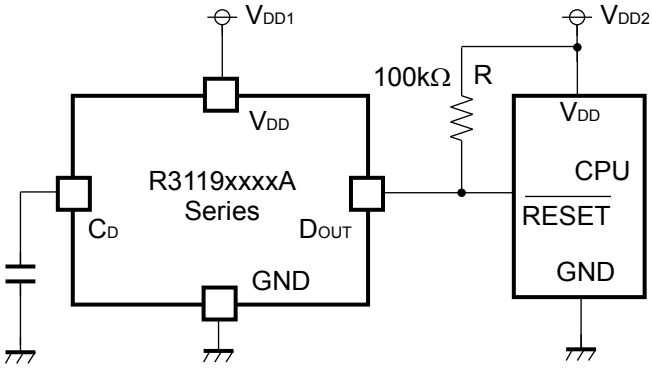
TYPICAL APPLICATION

- **R3119xxxxA (C_D pin type)**

(1) Input Voltage to R3119xxxxA is equal to Input Voltage to CPU

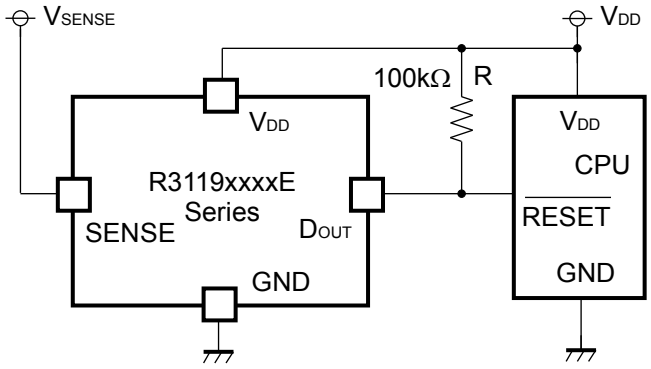


(2) Input Voltage to R3119xxxxA is unequal to Input Voltage to CPU

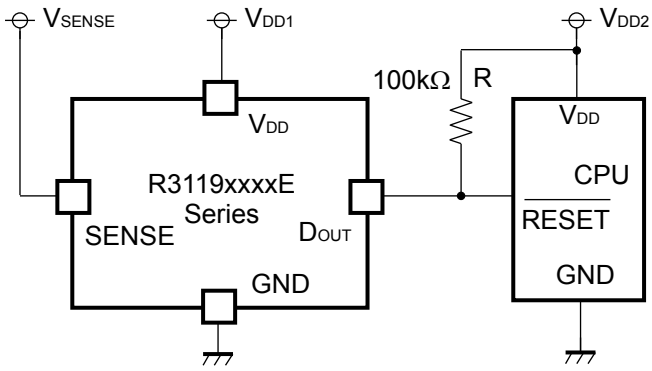


- **R3119xxxxE (SENSE pin type)**

(1) Input Voltage to R3119xxxxE is equal to Input Voltage to CPU

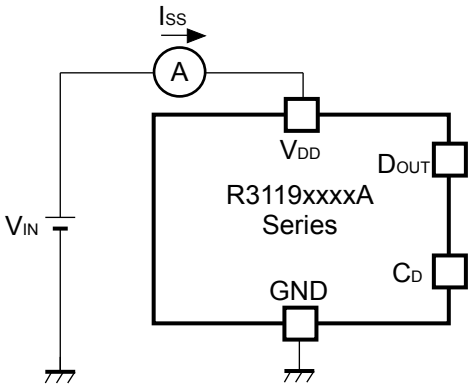


(2) Input Voltage to R3119xxxxE is unequal to Input Voltage to CPU

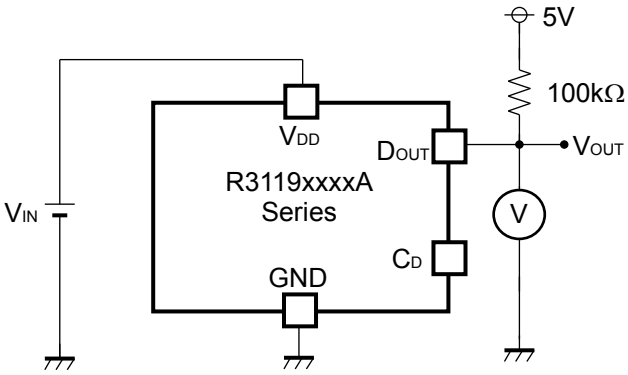


TEST CIRCUITS

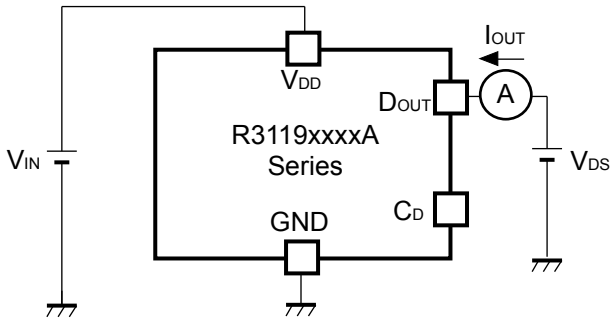
- **R3119xxxxA (C_D pin type)**



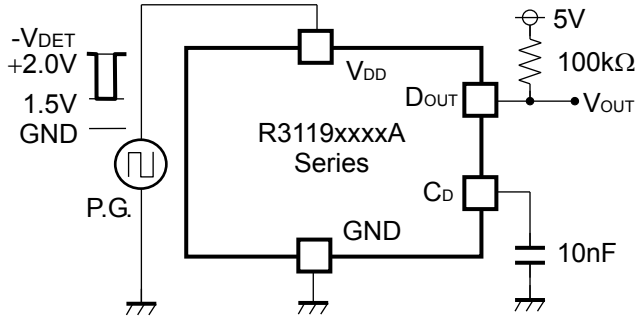
Supply Current Test Circuit



Detector Threshold Test Circuit

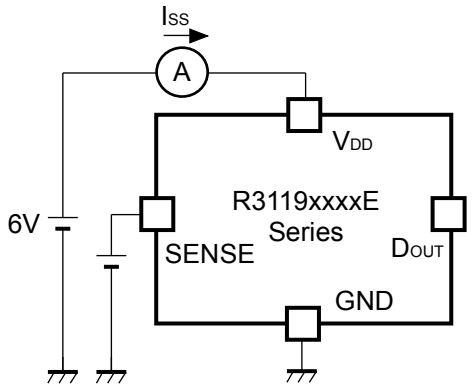


Nch Driver Output Current Test Circuit

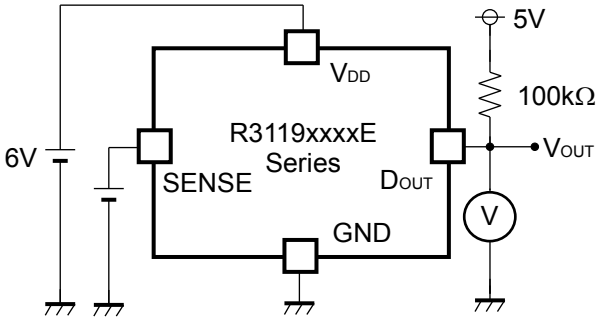


Output Delay Time Test Circuit

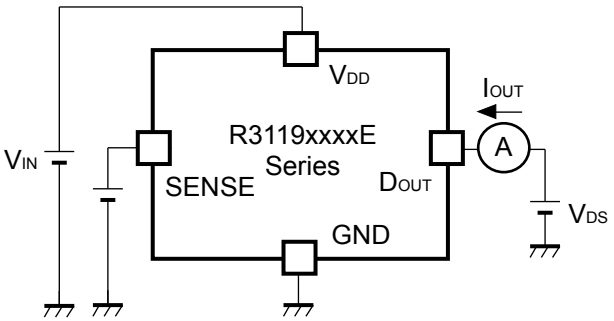
- **R3119xxxxE (SENSE pin type)**



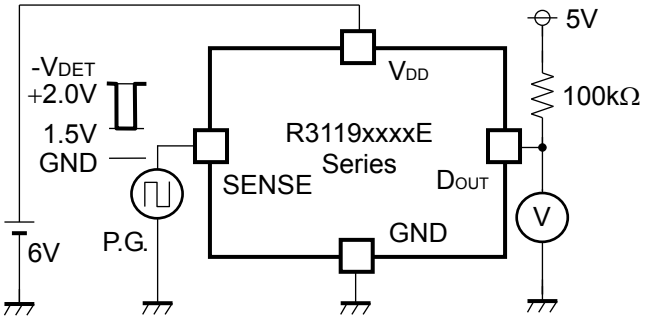
Supply Current Test Circuit



Detector Threshold Test Circuit



Nch Driver Output Current Test Circuit

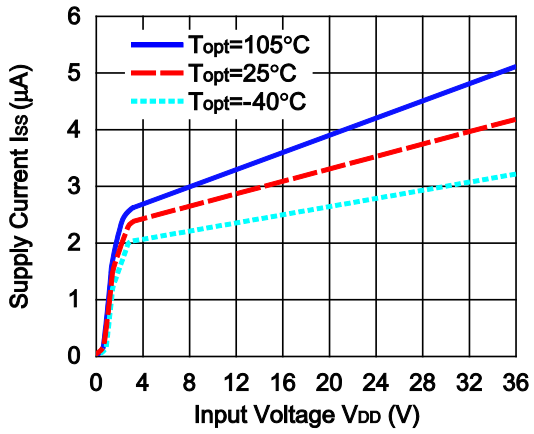


Output Delay Time Test Circuit

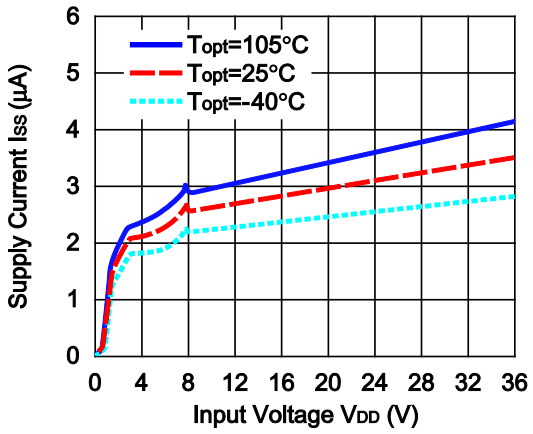
TYPICAL CHARACTERISTICS

1) Supply Current vs. Input Voltage

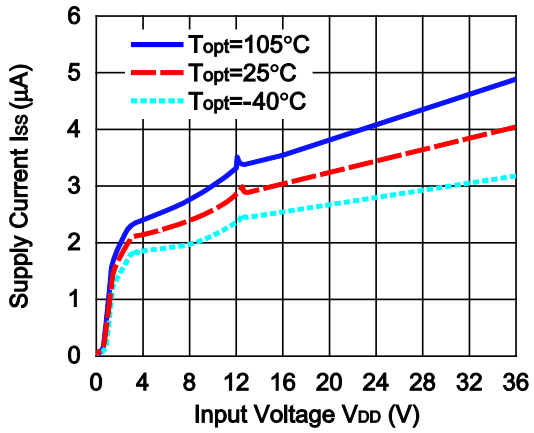
R3119x023A



R3119x077A

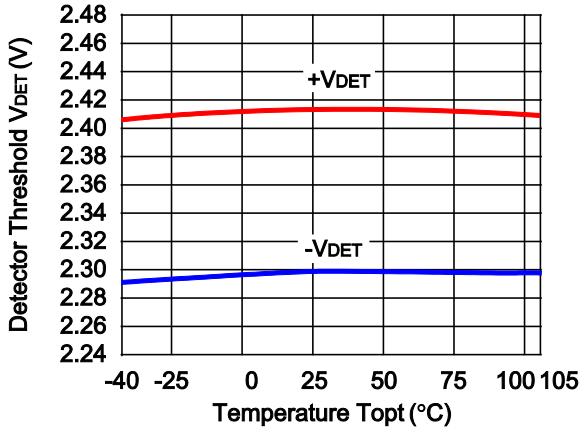


R3119x120A

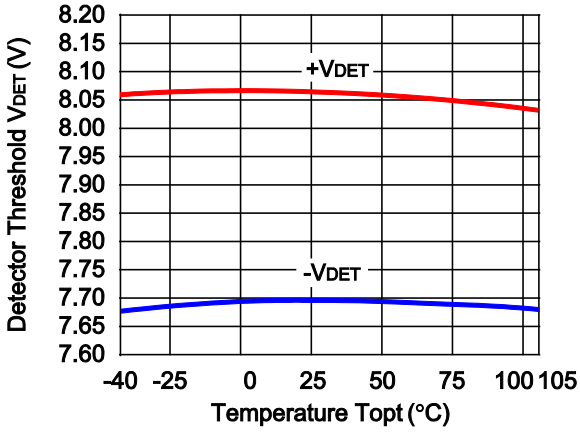


2) Detector Threshold vs. Temperature

R3119x023A/E



R3119x077A/E



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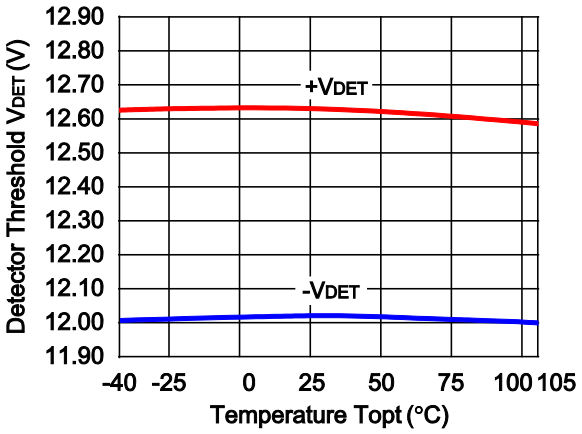
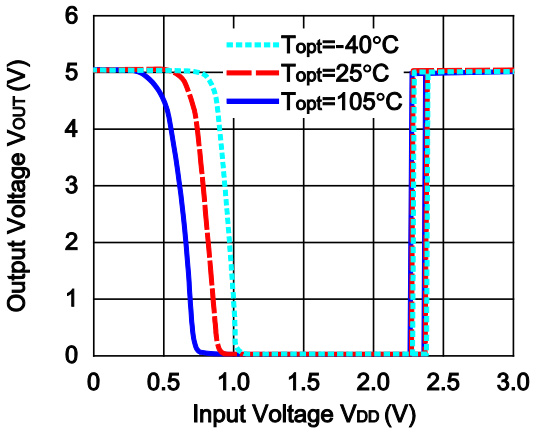


3) Output Voltage vs. Input Voltage

R3119x023A/E



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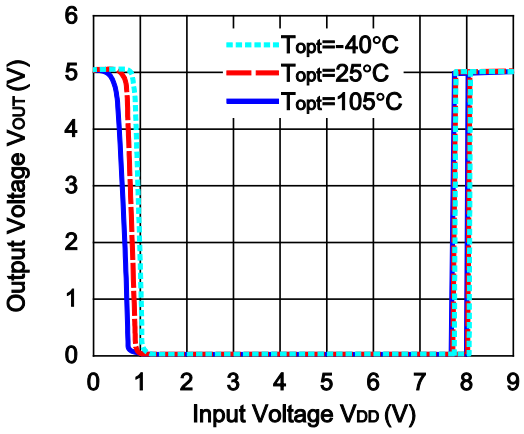
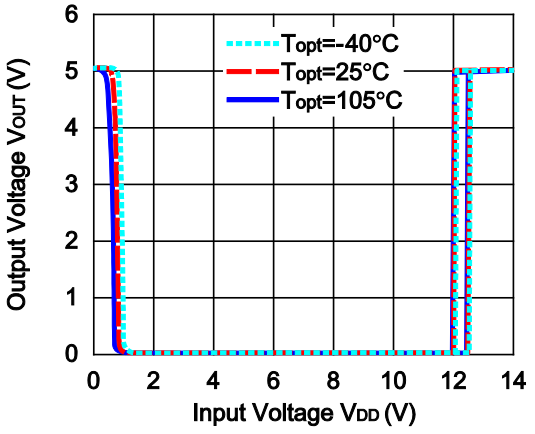
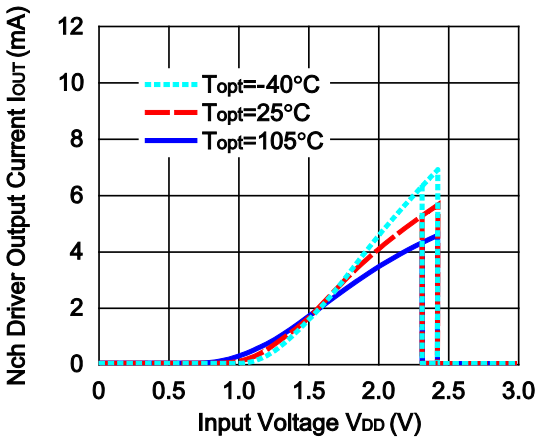


R3119x120A/E



4) Nch Driver Output Current vs. Input Voltage

R3119x023A



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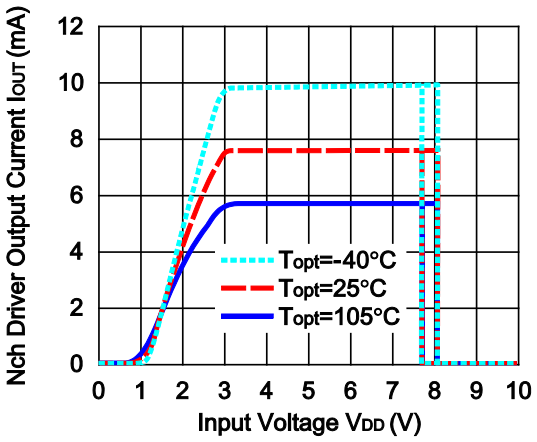

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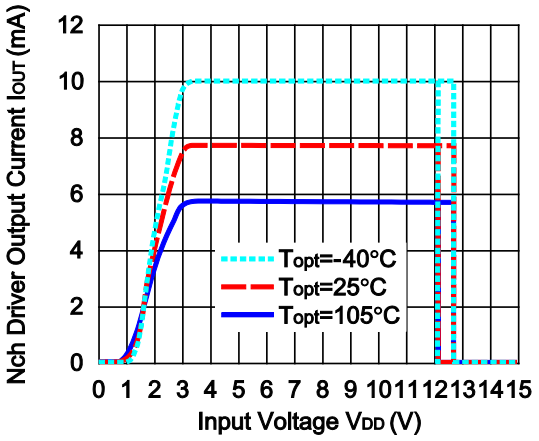
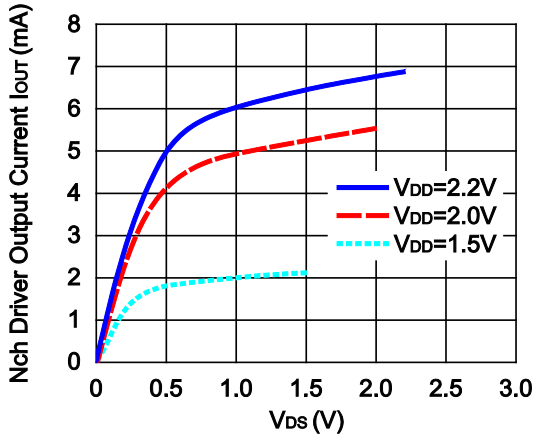


5) Nch Driver Output Current vs. V_{DS}

R3119x023A



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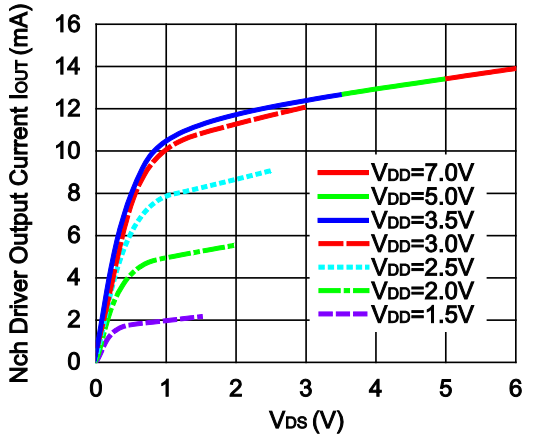

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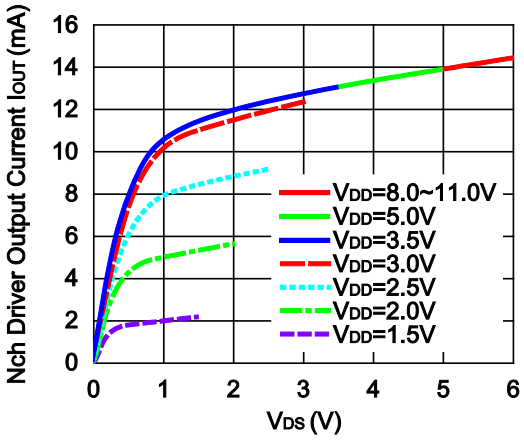
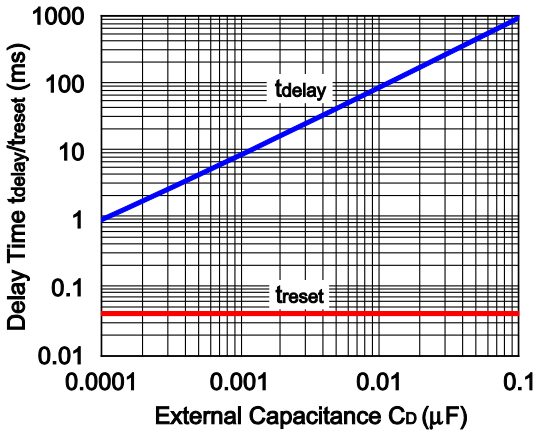


6) Output Delay Time vs. External Capacitance (Topt=25°C)

R3119x023A



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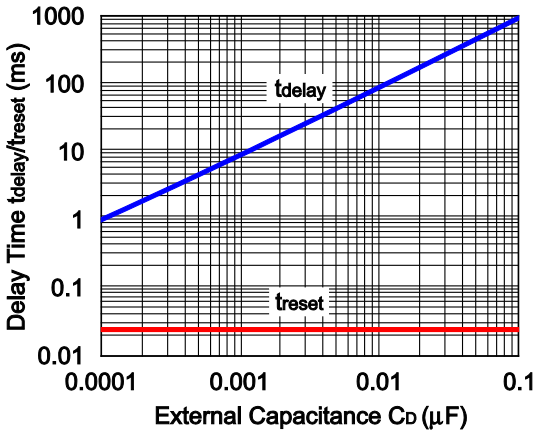

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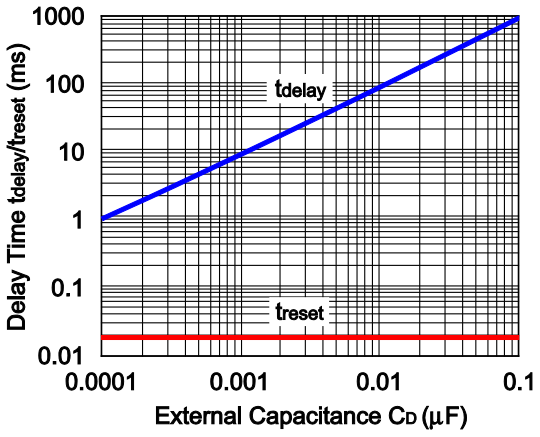
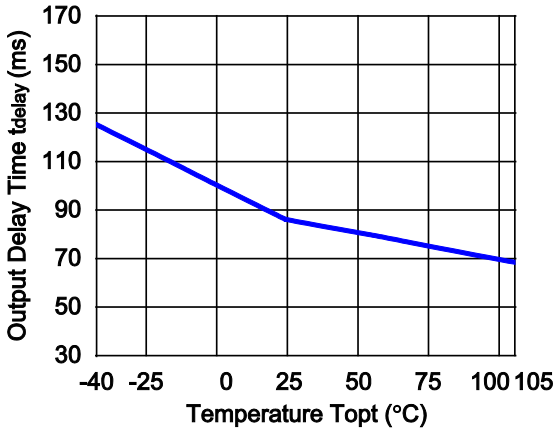


7) Output Delay Time vs. Temperature (C_D=0.01µF)

R3119x023A



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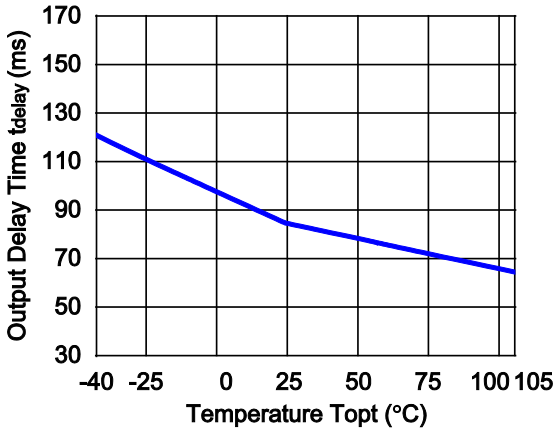

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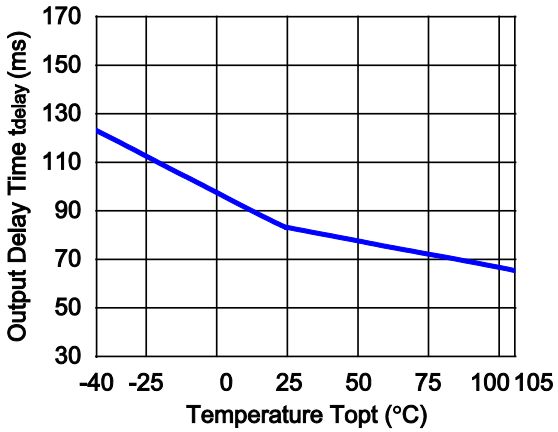
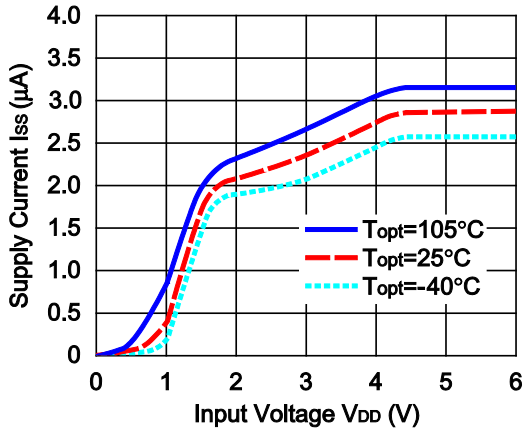
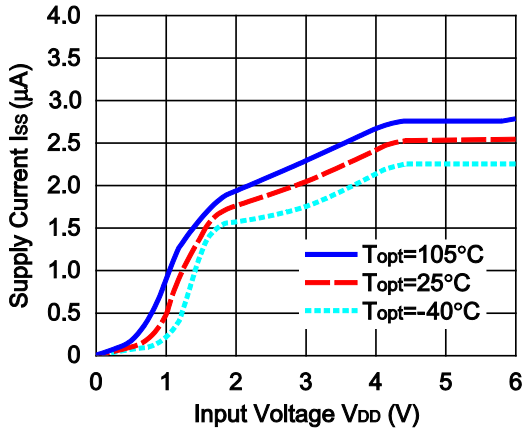


8) Supply Current vs. Input Voltage

R3119xxxxE (at released)

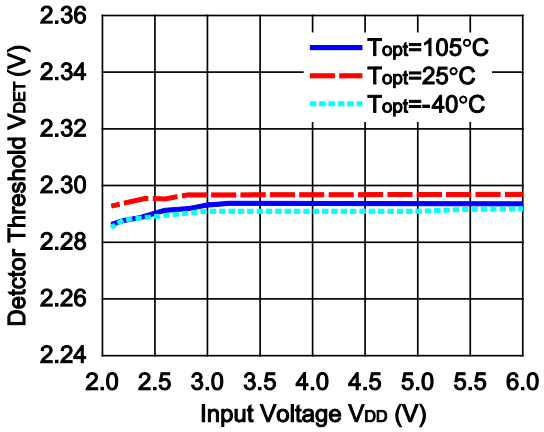


R3119xxxxE (at detected)

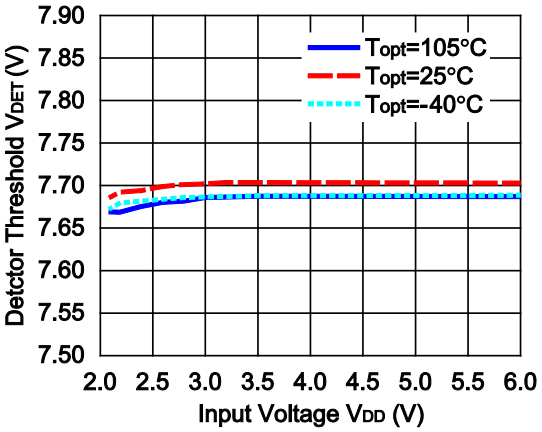


9) Detector Threshold vs. Input Voltage

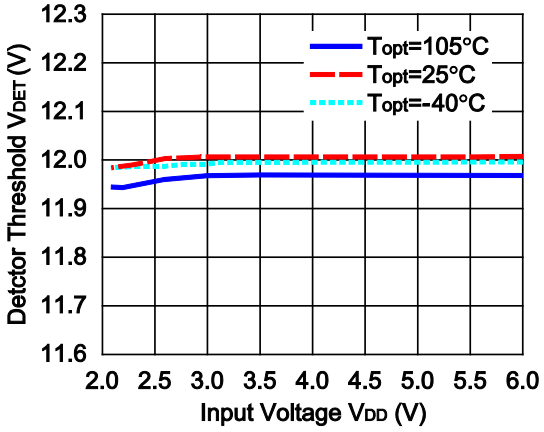
R3119x023E



R3119x077E

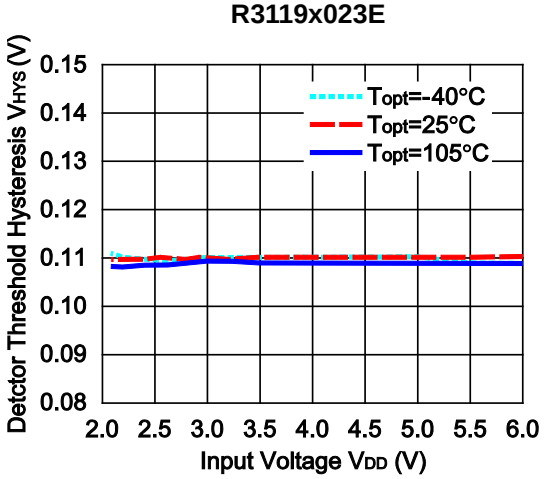


R3119x120E

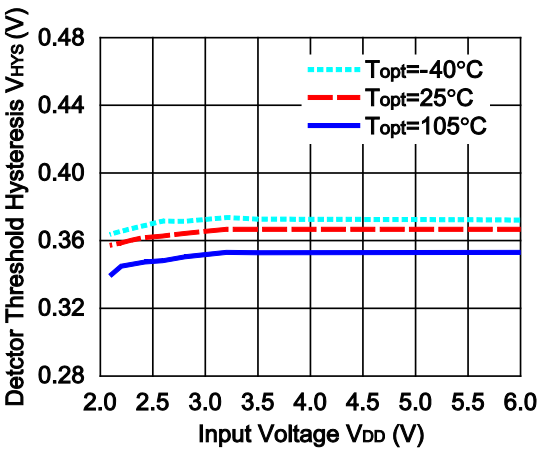


10) Detector Threshold Hysteresis vs. Input Voltage

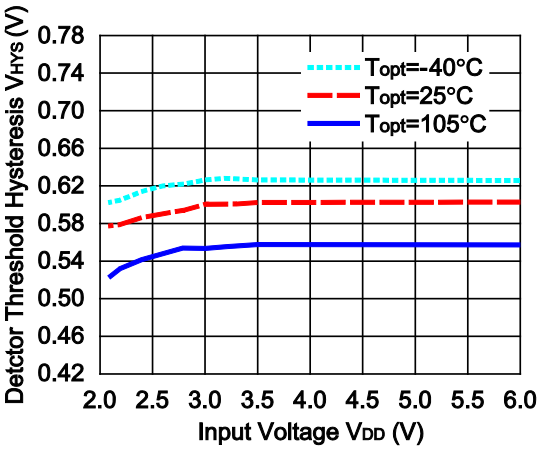
R3119x023E



R3119x077E

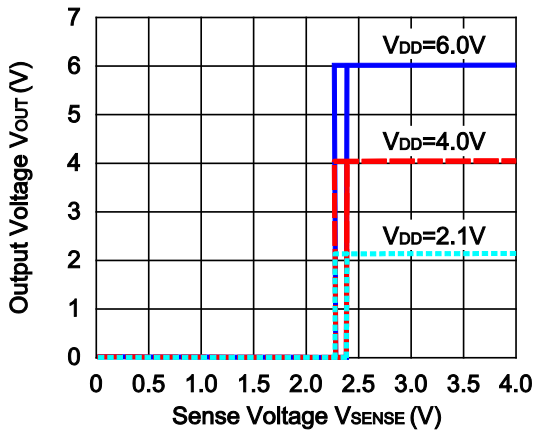


R3119x120E



11) Output Voltage vs. SENSE pin Input Voltage (Topt=25°C) (DOUT pull up to VDD with 100kΩ)

R3119x023E



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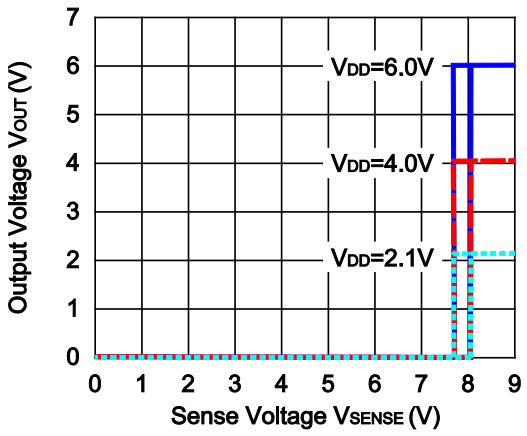

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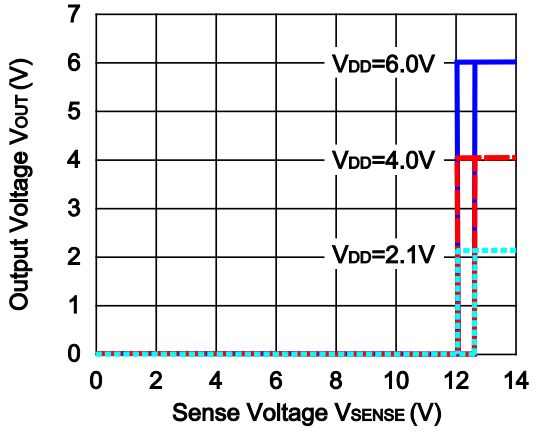
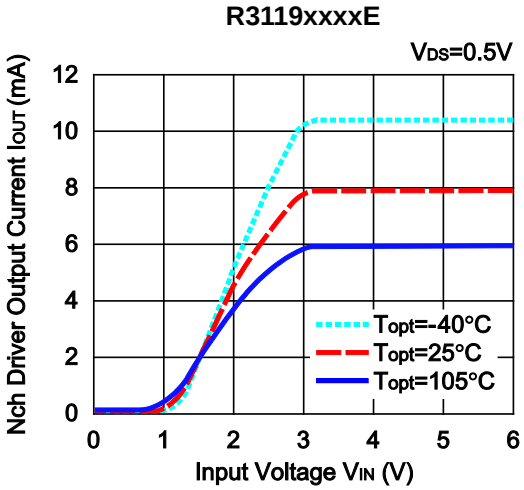
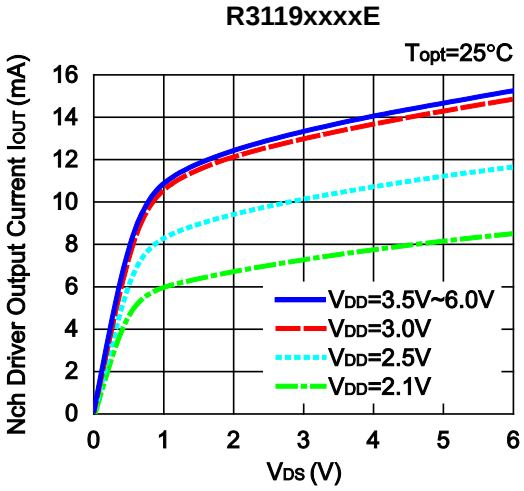


12) Nch Driver Output Current vs. Input Voltage



13) Nch Driver Output Current vs. V_{DS}



TECHNICAL NOTES

When connecting resistors to the device's input pin

When connecting a resistor (R1) to an input of this device, the input voltage decreases by [Device's Consumption Current] x [Resistance Value] only. And, the cross conduction current*1, which occurs when changing from the detecting state to the release state, is decreased the input voltage by [Cross Conduction Current] x [Resistance Value] only. And then, this device will enter the re-detecting state if the input voltage reduction is larger than the difference between the detector voltage and the released voltage.

When the input resistance value is large and the VDD is gone up at mildly in the vicinity of the released voltage, repeating the above operation may result in the occurrence of output.

As shown in Figure A/B, set R1 to become 100 kΩ or less as a guide, and connect C_{IN} of 0.1 µF and more to between the input pin and GND. Besides, make evaluations including temperature properties under the actual usage condition, with using the evaluation board like this way. As a result, make sure that the cross conduction current has no problem.

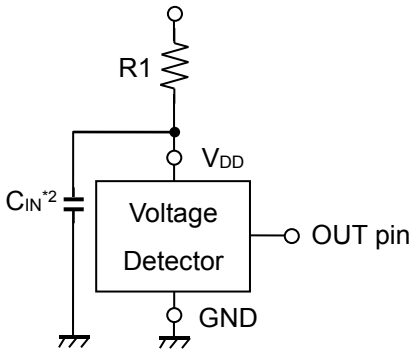


Figure A

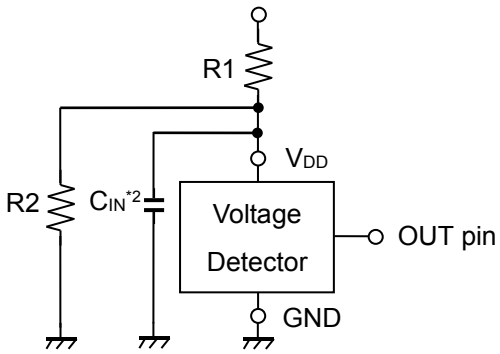


Figure B

*1 In the CMOS output type, a charging current for OUT pin is included.

*2 Note the bias dependence of capacitors.

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